
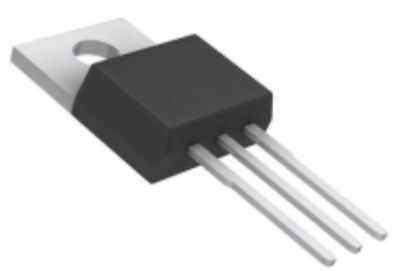


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|---|--|
|  | <h2 style="color: red;">HGTP5N120BND</h2> |
| | <p>Hersteller-Teilenummer: HGTP5N120BND</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: IGBT 1200V 21A 167W TO220AB</p> <p>Datenblätter: 1.HGTP5N120BND.pdf 2.HGTP5N120BND.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 2629 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
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| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|---|---|
| Teilenummer | HGTP5N120BND |
| Hersteller | AMI Semiconductor / ON Semiconductor |
| Beschreibung | IGBT 1200V 21A 167W TO220AB |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-IGBTs- |
| Teilstatus | 2629 pcs Stock |
| detaillierte Beschreibung | IGBT NPT 1200V 21A 167W Through Hole TO-220AB |
| Serie | - |
| Eingabetyp | Standard |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Through Hole |
| Leistung - max | 167W |
| Verpackung / Gehäuse | TO-220-3 |
| Supplier Device-Gehäuse | TO-220AB |
| Rückwärts-Erholzeit (Trr) | 65ns |
| Strom - Kollektor (Ic) (max) | 21A |
| Spannung - Kollektor-Emitter-Durchbruch (max) | 1200V |
| IGBT-Typ | NPT |
| VCE (on) (Max) @ Vge, Ic | 2.7V @ 15V, 5A |
| Strom - Collector Pulsed (Icm) | 40A |
| Schaltenergie | 450µJ (on), 390µJ (off) |
| Gate-Ladung | 53nC |
| Td (ein / aus) bei 25 ° C | 22ns/160ns |
| Testbedingung | 960V, 5A, 25 Ohm, 15V |
| Verpackung | Tube |
| Bleifreier Status / RoHS-Status | Lead free / RoHS Compliant |
| Feuchtigkeitsempfindlichkeitsniveau (MSL) | 1 (Unlimited) |

HGTP5N120BND ist neu im Original, Suche HGTP5N120BND Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie HGTP5N120BND AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage HGTP5N120BND: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|---|---|---|
|  <p>HGTP5N120CN Intersil HGTP5N120CN Intersil</p> |  <p>HGTP7N60A4 G7N60A4 FSC HGTP7N60A4 G7N60A4 FSC</p> |  <p>HGTP7N60A4 AMI Semiconductor / ON Semiconductor IGBT 600V 34A 125W TO220AB</p> |  <p>HGTP3N60A4_0846+ FAIRCHI FAIRCHI TO-220</p> |
|  <p>HGTP3N60A4G3N60A4 FSC FSC TO220</p> |  <p>HGTP5N120BN Intersil HGTP5N120BN Intersil</p> |  <p>HGTP7N60A4 Fairchild/ON Semiconductor IGBT 600V 34A 125W TO220AB</p> |  <p>HGTP5N120BND Fairchild/ON Semiconductor IGBT 1200V 21A 167W TO220AB</p> |

heiße Teile

Mehr

| | | | | |
|-----------------|-----------------|----------------|-----------------|-----------------|
| ⊗ HGTP10N120BN | ↔ HGTP10N40C1 | ⇒ HGTP10N40E1D | D HGTP10N40F1D | ⇒ HGTP10N50C1 |
| ⊣ HGTP11N120CN | ⊗ HGTP11N120CND | D HGTP12N60A4 | ⇒ HGTP12N60A4 | ⇒ HGTP12N60A4D |
| ⊗ HGTP12N60A4D | ⊣ HGTP12N60B3 | ⊗ HGTP12N60B3D | ↔ HGTP12N60C3 | ⇒ HGTP12N60C3 |
| D HGTP14N36G3VL | ⊗ HGTP14N40F3VL | ⊣ HGTP14N41G3 | ⊗ HGTP15N120C3 | ⇒ HGTP15N40C1 |
| ⇒ HGTP15N50E1 | ↔ HGTP1N120BND | ⊗ HGTP1N120CND | ⊣ HGTP20N35G3VL | ⇒ HGTP20N36G3VL |
| ↔ HGTP20N60A4 | ⇒ HGTP20N60A4 | D HGTP20N60B3 | ⊗ HGTP20N60B3D | ⊣ HGTP20N60C3 |
| ⊗ HGTP20N60C3D | D HGTP2N120BN | ⇒ HGTP2N120BND | ↔ HGTP2N120CN | ⇒ HGTP2N120CN |
| ⊣ HGTP2N120CND | ⊗ HGTP3N60A4 | ↔ HGTP3N60A4 | ⇒ HGTP5N120BND | ⇒ HGTP7N60A4 |
| ⊗ HGTP7N60A4 | ⊣ HGTP7N60A4D | ⊗ HGTP7N60A4D | D HGTP7N60B3 | ⇒ HGTP7N60B3D |
| ↔ HGTP7N60B3D | ⊗ HGTP7N60C3 | ⊣ HGTP7N60C3D | ⊗ HGTP7N60C3D | ⇒ HGTP7NA60A4D |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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